Research Article
Defects-Induced Hot Spots in TATB

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We investigate the interaction between the laser and energetic materials with different defects. The three-dimensional models of triaminotrinitrobenzene (TATB) explosives containing spherical pores, craters, and cracks are established, respectively. The laser ignition process of TATB is simulated with three-dimensional finite difference time domain (3D-FDTD) method to study the electromagnetic field distribution surrounding these defects with 355 nm laser incidence. It indicates that the larger defects in the TATB energetic materials have the stronger electric field modulations to initial incident laser for all the three defects, which is easier to lead to the generation of hot spots. Furthermore, TATB materials with spherical pore defects and crater defects are easier to form hot spots than those with narrow crack defects.

1. Introduction

The ignition of explosives has been studied for so many years. There are several conventional means for the ignition systems, such as electric spark ignition and electric bridge-wire ignition. However, due to the interference of static electricity, radio frequency, electromagnetic field, and other unpredictable factors, traditional ignition technologies of explosives materials tend to explode by mistake or fail to work.

Laser ignition technology, introduced by Brish et al. [1] and Yang and Menichelli [2] in the late sixties and early seventies of last century, has been recognized as a safe and reliable means which has extensive potential applications in the aerospace and military field owing to the laser’s high intensity and good direction. The first discussion of laser ignition mechanisms is also discussed in [1]. Generally speaking, there are two possible ignition mechanisms used to interpret the explosion phenomenon: thermal ignition mechanism and impulse ignition mechanism. In the thermal mechanism, the intense local heating by the laser pulse causes the rate of chemical reactions within the materials to accelerate sharply. It requires flux densities in the neighborhood of 1 kW/cm² or less and pulse durations of about 1 ms or longer. But in the impulse ignition mechanism, where the chemical reactions are accelerated by a strong laser-generated shock wave, it needs more intense and shorter duration by factors of about 10⁶ with the similar energy content than that in the thermal ignition mechanism [3]. The term “hot spots” represents the regions which can couple efficiently the locally higher temperature and ultimately initiation in materials [4]. Because of their modulations for the laser electromagnetic field, defects (voids, bubbles, etc.) in the explosives materials can result in the generation of hot spots.

Based on the thermal ignition mechanism, we investigated the interaction between the laser and energetic materials with different defects in our work. Triaminotrinitrobenzene (TATB) explosives were firstly characterized with the Scanning Electron Microscopy (SEM). Three-dimensional (3D) models of TATB energetic materials containing spherical pore, crater, and crack defects were established, respectively. The laser ignition process of TATB was simulated with three-dimensional finite difference time domain (3D-FDTD)
method [5–8] to study the electromagnetic field distribution (in proportion to the flux density $I$) surrounding these defects with 355 nm laser incidence. The simulated results of electric field amplitude distributions and the number of high-intensity spots in TATB materials were analyzed to investigate the effect of the three kinds of defects on the generation of hot spots.

### 2. Models and FDTD Method

The TATB explosives with many microdefects, including spherical pores, craters, and cracks, were characterized with the Scanning Electron Microscopy (SEM) shown in Figure 1. It indicated that all the defect sizes are in the micron or submicron level (shown in Table 1). As it is difficult to know the light modulation of only one of these defects through experiments, in this work we utilized the 3D-FDTD methods to simulate the modulation of each defect to the incident laser. According to these SEM images, we constructed the three-dimensional sphere model, rotated parabolic body model, and straight triangular prism model, respectively, to fit the air area as circled in Figure 1, as their three-dimensional profiles showed in Figure 2. We supposed that all the defects lie in the top surface of the TATB explosives. Their equations in Cartesian coordinates are as follows.

#### Sphere

$$
(z - z_0 + h - r)^2 \leq r^2 - \left[ (x - x_0)^2 + (y - y_0)^2 \right]. \tag{1}
$$

#### Rotated parabolic body

$$
z \geq \frac{4b}{a^2} \left[ (x - x_0)^2 + (y - y_0)^2 \right] + z_0 - b. \tag{2}
$$

### Table 1: The size range of different defects.

<table>
<thead>
<tr>
<th>Defects</th>
<th>SEM Size Range</th>
<th>FDTD Simulations</th>
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<tr>
<td>Spherical pores</td>
<td>$r = 0.5–1.5 \mu m$</td>
<td>$r = 20–60\delta$</td>
</tr>
<tr>
<td>Craters ($a \geq b$)</td>
<td>$a = 0.5–3 \mu m$</td>
<td>$a = 20–100\delta$</td>
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<tr>
<td>Cracks ($d \geq w$)</td>
<td>$l = 0.5–3 \mu m$</td>
<td>$l = 20–100\delta$, $w = 0.2 \times l$</td>
</tr>
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![Figure 1: SEM of TATB explosives with different defects: (a) spherical pores, (b) craters, and (c) cracks.](image-url)
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Figure 2: The three-dimensional profiles of models for the microdefects in Figure 1: (a) sphere, (b) rotated parabolic body, and (c) straight triangular prism.

Straight triangular prism

\[
\begin{align*}
\text{for } z & \geq \frac{2d}{w} (x - x_0) + z_0 - d, \\
\text{for } z & \geq -\frac{2d}{w} (x - x_0) + z_0 - d, \\
y_0 - \frac{l}{2} & \leq y \leq y_0 + \frac{l}{2},
\end{align*}
\]

where \((x_0, y_0, z_0)\) is the coordinate of the symmetrical center of the top surface. \(r\) and \(h\) represent the radius and the depth of the spherical pores, respectively. \(a\) and \(b\) are the width and depth of the craters. \(l, d\) and \(w\) represent the length, the depth and the width of the cracks respectively. From the SEM, we assumed that \(a \geq b\), \(d \geq w\). For easy description, in our study we supposed that the depth/radius ratio of spherical pore defects \(R_s = h/r\), the depth/width ratio of crater defects \(R_c = b/a\), and the depth/width ratio of crack defects \(R_c = d/w\).

3. Results and Discussion

Equation (4) expounds the relationship of the flux density \(I\) and electric field amplitude \(|E|\). As we know, the flux density distribution can be analyzed by the electric field amplitude in the TATB explosives

\[I \propto |E|^2.\]  \hfill (4)

3.1. Spherical Pore Defects. In order to explore effects of the radius \(r\) of spherical pore defects and their depth \(h\) embedded in TATB explosives on the flux density distribution, we investigated the relationship between the electric field distribution and the depth/radius ratio \(R_s\). The size range of FDTD simulations is shown in Table 1. Figure 3 shows the maximum electric field \(|E|_{\text{max}}\) of some \(z\) planes at different \(R_s\) when \(r = 60\delta\). As the location of \(z\) plane changes, \(|E|_{\text{max}}\) fluctuates up and down at different \(z\) planes. However, the general trend increases gradually. Figure 4(a) shows the maximum electric field \(|E|_{\text{max}}\) of Plane \(xoz\) \((y = y_0)\) at the radius \(r = 40\delta\) and the whole simulation domain at \(r = 20\delta, 40\delta,\) and \(60\delta\) changing with the increasing \(R_s\). It is obvious that \(|E|_{\text{max}}\) of all the simulation domain is not obtained definitely at Plane \(xoz\). It is even much larger than that in the Plane \(xoz\). As \(R_s\) increases from 0.125 to 2.5, \(|E|_{\text{max}}\) for the whole space changes in the range of 2.0–2.7 V/m, and the flux density reaches a factor (light intensity enhancement factor, LIEF) of 4–7.29 compared with the initial incident laser. It is clear that the larger the radius of sphere defects is, the stronger its modulation to incident laser is. When the size of spherical pores is small, the modulation effect is weak because of the minor scattering.
surface. However, when \( r \) gets to \( 60\delta \), the reflecting surface increases owing to the increasing surface area. At this time, even total reflection may appear. So the modulation to initial laser is stronger when sphere is larger.

Besides, we use the term "high-intensity spot" in this work to express the region where the electric field amplitude \( |E| \geq 2.0 \text{ V/m} \) and the number of high-intensity spots was counted and exported by computer program. Figure 4(b) shows the number of high-intensity spots in the whole simulation space. It revealed that the number increases firstly with the increase of \( R_s \) and then decreases to a stable range when \( R_s \geq 2 \), in which the defects have been completely embedded into the explosives. As the radius \( r \) increases, the number of high-intensity spots increases. It shows that the number of high-intensity spots induced by spherical pore defects when \( r = 1.8 \mu m \) (60\( \delta \)) has reached about 3 times of that when \( r = 1.2 \mu m \) (40\( \delta \)).

3.2. Crater Defects. The interaction between laser and TATB explosives containing crater defects is also studied.
Figure 5: (a) $|E|_{\text{max}}$ and (b) the number of high-intensity spots as the function of Rcr. 

Figure 6: Electric field amplitude distributions when $a = 100\delta$ and $Rcr = 0.5$: (a) Plane $xoz$ and (b) Plane $z198$ where the maximum electric field amplitude occurs.

Figure 5 shows the effects of the width $a$ and depth $b$ of crater defects (shown in Figure 2(b)) on the electric field distributions. Generally speaking, the maximum electric field $|E|_{\text{max}}$ increases firstly with the increasing depth/width ratio $Rcr$ and then decreases slowly. The larger the width of crater defects is, the stronger its modulation to incident laser is. When $a = 0.6 \mu m$ ($20\delta$), $|E|_{\text{max}}$ keeps basically in a stable value around 2.08 V/m and there is a small number of high-intensity spots. However, when $a$ gets to 1.8 $\mu m$ ($60\delta$), $|E|_{\text{max}}$ is mainly in the range of 2.1–2.3 V/m with the LIEF from 4.41 to 5.29 as Rcr changes. The number of high-intensity spots increases to dozens. Finally, when $a$ reaches up to 3 $\mu m$ ($100\delta$), most of the maximum electric field $|E|_{\text{max}}$ keep in the level above 2.55 V/m with the LIEF more than 6.5 times compared to the initial incident laser. Similar to the spherical pore defects, as the width of crater defects $a$ increases, the number of high-intensity spots increases. It shows that the number of high-intensity spots when $a = 3 \mu m$ has reached about 4 times of that when $a = 1.8 \mu m$.

Figure 6, respectively, displays the electric field amplitude distributions of Plane $xoz$ ($y = y0$) and Plane $z198$ (where the maximum electric field amplitude occurs) when $a = 100\delta$, $Rcr = 0.5$. As the defects lie in the top surface, the electric field near the top surface is higher. And the maximum electric field appears in Plane $z198$ which is nearly close to crater defects.

3.3. Crack Defects. According to Figure 2(c), we investigated the effect of the depth/width ratio Rck of crack defects with
various length $l = 20\delta$, 60\delta, and 100\delta on the propagation and scattering of electromagnetic fields within the TATB explosives. From the SEM image in Figure 1(c), we assumed the width $w = l/5$. Figure 7(a) displays the maximum electric field amplitude $|E|_{\text{max}}$ changing with the increasing Rck. As the length of crack defects changes, most $|E|_{\text{max}}$ lie in the range of 2.1–2.3 V/m with the number of high-intensity spots less than 30. As the length of crack defects increases, there are also some enhanced electric field areas. However, it is not so many as those of crater and crack defects because of the narrow width.

The Rck for gaining the maximum of $|E|_{\text{max}}$ is different for different lengths. When $l$ is about 0.6 $\mu$m (20\delta), the maximum, 2.47 V/m, is obtained at Rck = 3.5. However, for $l = 1.8$ $\mu$m (60\delta) and 3 $\mu$m (100\delta), Rck changes to 4.5 and 2.5 with their $|E|_{\text{max}}$ values to 2.73 V/m and 2.54 V/m, respectively. Even so, the maximal number of high intensity spots is acquired at $l = 100\delta$ when Rck = 2.5. Figure 8 shows the electric field amplitude distributions in the $z$ plane of $|E|_{\text{max}}$ at the length $l = 100\delta$ and width $w = 20\delta$. It indicates that every $|E|_{\text{max}}$ lies in the $z$ plane which is on (Plane $z=200$) or near (Plane $z=187$, $z=193$) the top surface. Especially, the $|E|_{\text{max}}$ lie in the $z$ plane of the bottom of crack defects (Plane $z=141$ for Rck = 3, Plane $z=121$ for Rck = 4).

From Figures 4, 5, and 7, we can deduce that the larger the defect in the TATB energetic material is, the stronger modulation to incident laser is, which is easier to generate hot spots. Moreover, spherical pore defects when $r = 1.8$ $\mu$m with $Rs$ increasing from 0.125 to 2.5. And the light intensity enhancement factor (LIEF) reaches 4–7.29 compared with the initial laser. As the radius $r$ increases, electric field amplitude strengthens and the number of high-intensity spots increases. The number of high-intensity spots induced by spherical pore defects when $r = 1.8$ $\mu$m reaches about 3 times of that when $r = 1.2$ $\mu$m. Similar to the spherical pore defects, as the width $a$ of crater defects increases from 0.6 to 3 $\mu$m, the number of high-intensity spots increases to several hundred. When $a = 3$ $\mu$m, the number of high-intensity spots has reached about 4 times of that when $a = 1.8$ $\mu$m with most of the maximum electric field in the level above 2.55 V/m (LIEF ≥ 6.5). However, as the length of crack defects $l$ changes from 0.6 to 3 $\mu$m with the width $w = l/5$, most $|E|_{\text{max}}$ lie in the range of 2.1–2.3 V/m with the number of high-intensity spots less than 30 because of the narrow width.

For all the three defects, the larger the defect in the TATB energetic material is, the stronger the modulation to incident laser is, which is easier to lead to the generation of hot spots. Furthermore, spherical pore defects when $r = 1.8$ $\mu$m with

4. Conclusions

The laser interactions with TATB explosives including different defects (spherical pores, craters, and cracks) were investigated, respectively, with the three-dimensional finite difference time domain method. The modulations of these defects to incident laser were analyzed with the maximum electric field amplitude and the number of high-intensity spots.

The results indicate that the maximum electric field $|E|_{\text{max}}$ of spherical pores changes in the range of 2.0–2.7 V/m as the radius $r$ changes from 0.6 to 1.8 $\mu$m with the depth/radius ratio $Rs$ increasing from 0.125 to 2.5. And the light intensity enhancement factor (LIEF) reaches 4–7.29 compared with the initial laser. As the radius $r$ increases, electric field amplitude strengthens and the number of high-intensity spots increases. The number of high-intensity spots induced by spherical pore defects when $r = 1.8$ $\mu$m reaches about 3 times of that when $r = 1.2$ $\mu$m. Similar to the spherical pore defects, as the width $a$ of crater defects increases from 0.6 to 3 $\mu$m, the number of high-intensity spots increases to several hundred. When $a = 3$ $\mu$m, the number of high-intensity spots has reached about 4 times of that when $a = 1.8$ $\mu$m with most of the maximum electric field in the level above 2.55 V/m (LIEF ≥ 6.5). However, as the length of crack defects $l$ changes from 0.6 to 3 $\mu$m with the width $w = l/5$, most $|E|_{\text{max}}$ lie in the range of 2.1–2.3 V/m with the number of high-intensity spots less than 30 because of the narrow width.

For all the three defects, the larger the defect in the TATB energetic material is, the stronger the modulation to incident laser is, which is easier to lead to the generation of hot spots. Furthermore, spherical pore defects when $r = 1.8$ $\mu$m with...
Figure 8: Electric field amplitude distributions in the $z$ plane of $|E|_{\text{max}}$ of cracks with different $R_{ck}$ at the length $l = 100\delta$ and width $w = 20\delta$: (a) $R_{ck} = 1$, Plane $z = 200$; (b) $R_{ck} = 2$, Plane $z = 187$; (c) $R_{ck} = 3$, Plane $z = 141$; (d) $R_{ck} = 4$, Plane $z = 121$; (e) $R_{ck} = 5$, Plane $z = 193$. 
depth/radius ratio from 0.75 to 1.75 and crater defects when \( a = 3 \mu m \) with depth/width ratio from 0.5 to 1.0 are easier ways to generate hot spots than crack defects with \( w = l/5 \).

**Conflict of Interests**

The authors declare that there is no conflict of interests regarding the publication of this paper.

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